



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



Features

- Low gate charge
- 100% avalanche tested
- Improved dv/dt capability
- RoHS compliant
- Halogen free package
- JEDEC Qualification
- Improved ESD performance

N-channel MOSFET

BV_{DSS}	I_D	$R_{DS(on)}$
650V	4.0A	< 2.4Ω



Device	Package	Marking	Remark
GP2M004A065HG	TO-220	GP2M004A065HG	RoHS
GP2M004A065FG	TO-220F	GP2M004A065FG	RoHS

Absolute Maximum Ratings

Parameter	Symbol	GP2M004A065HG	GP2M004A065FG	Unit
Drain-Source Voltage	V_{DSS}	650		V
Gate-Source Voltage	V_{GS}	±30		V
Continuous Drain Current	I_D	$T_C = 25\text{ °C}$	4	4 *
		$T_C = 100\text{ °C}$	2.63	2.63 *
Pulsed Drain Current (Note 1)	I_{DM}	16	16 *	A
Single Pulse Avalanche Energy (Note 2)	E_{AS}	206		mJ
Repetitive Avalanche Current (Note 1)	I_{AR}	4		A
Repetitive Avalanche Energy (Note 1)	E_{AR}	9.84		mJ
Power Dissipation	P_D	$T_C = 25\text{ °C}$	98.4	32.8
		Derate above 25 °C	0.78	0.26
Peak Diode Recovery dv/dt (Note 3)	dv/dt	4.5		V/ns
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55~150		°C
Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds	T_L	300		°C

* Limited only by maximum junction temperature

Thermal Characteristics

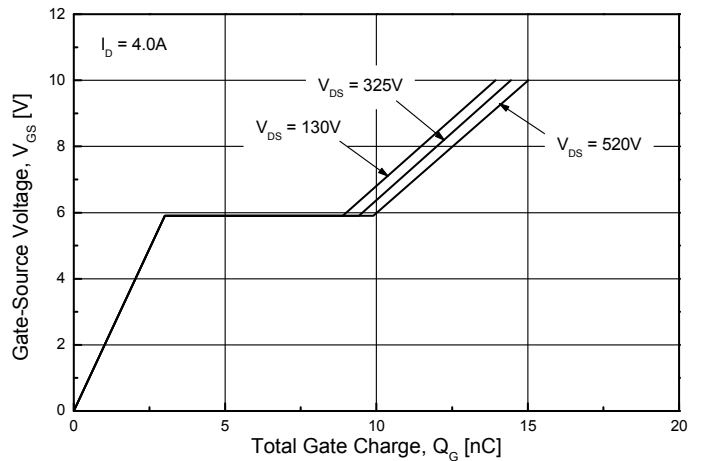
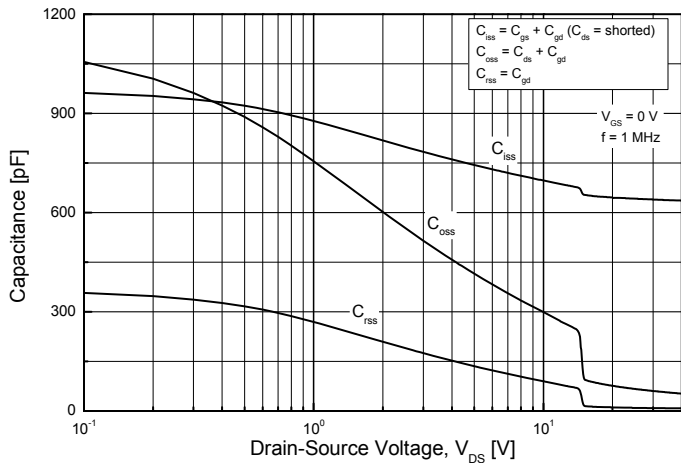
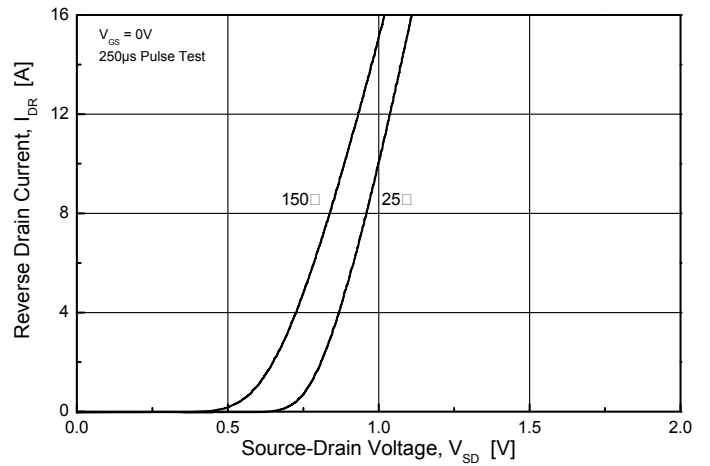
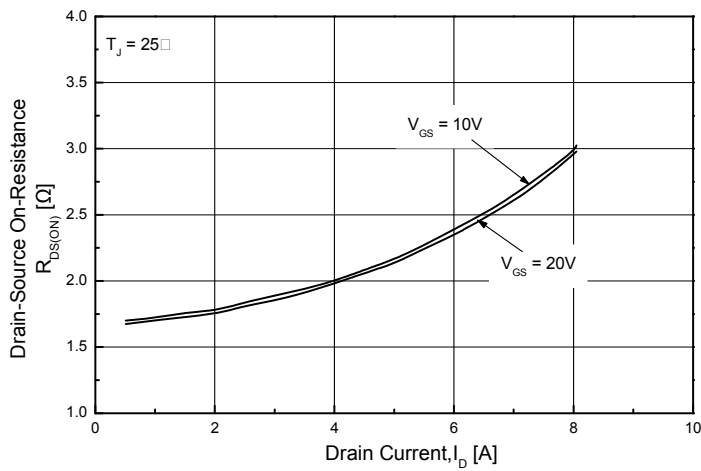
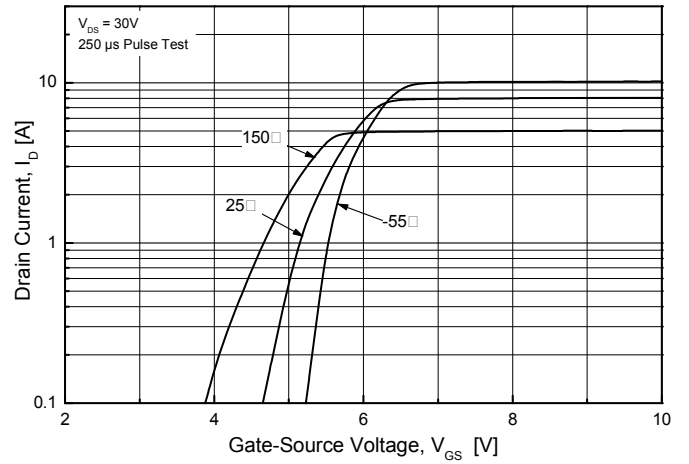
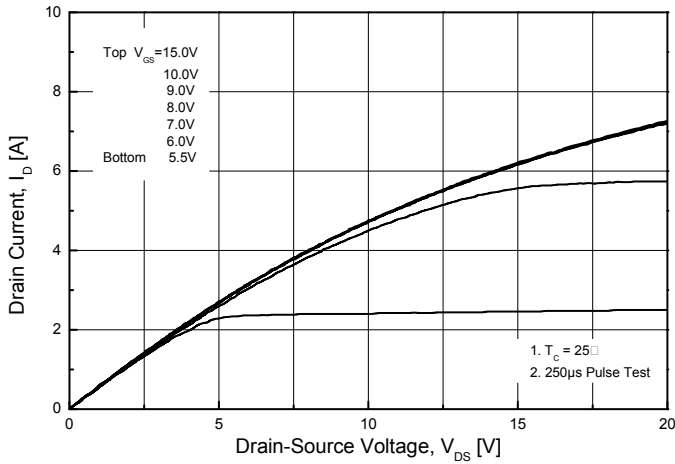
Parameter	Symbol	GP2M004A065HG	GP2M004A065FG	Unit
Maximum Thermal resistance, Junction-to-Case	$R_{θJC}$	1.27	3.8	°C/W
Maximum Thermal resistance, Junction-to-Ambient	$R_{θJA}$	62.5	62.5	°C/W

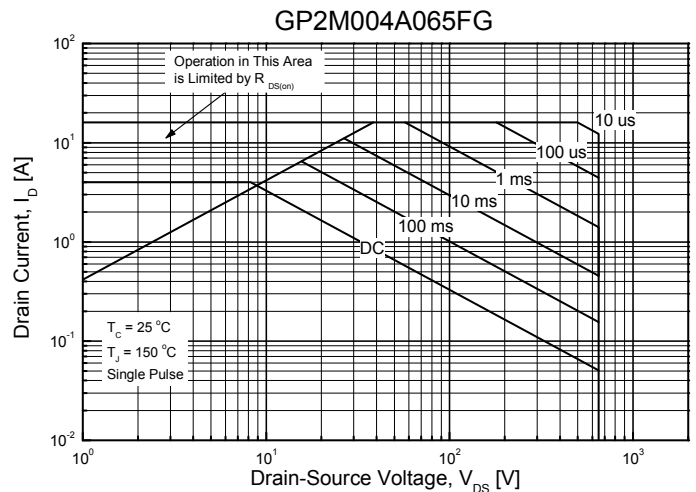
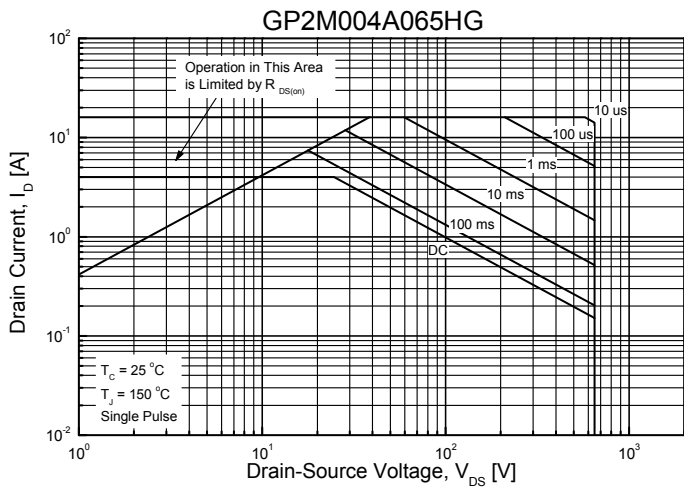
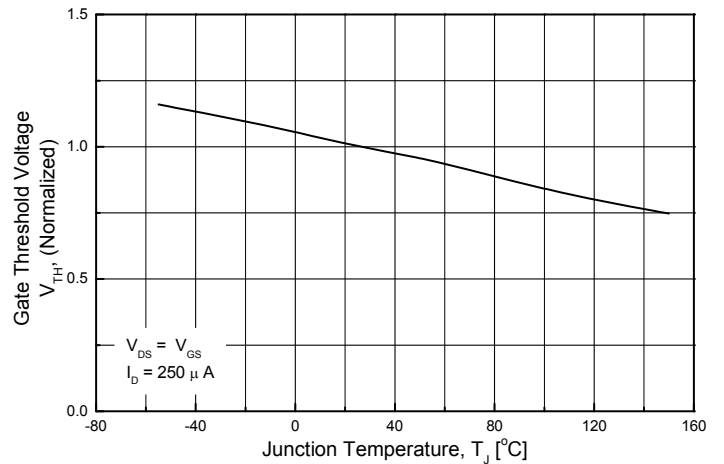
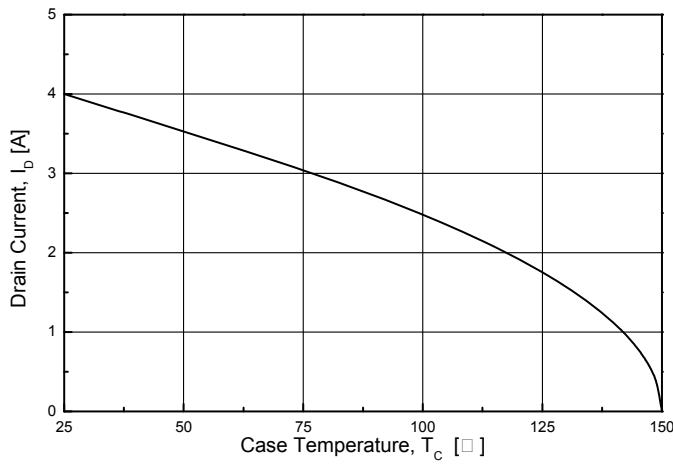
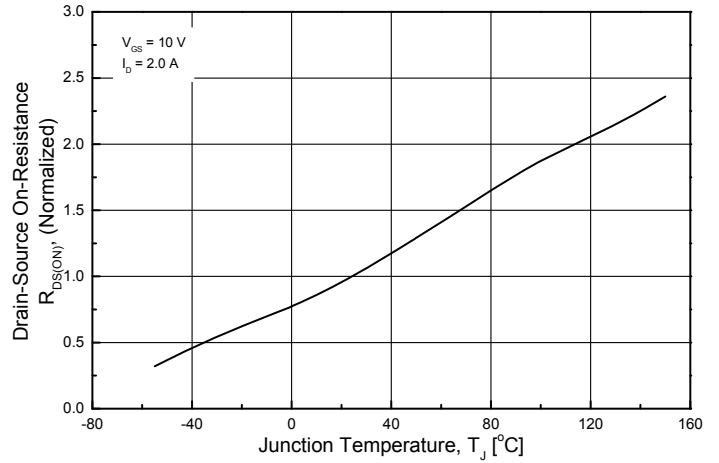
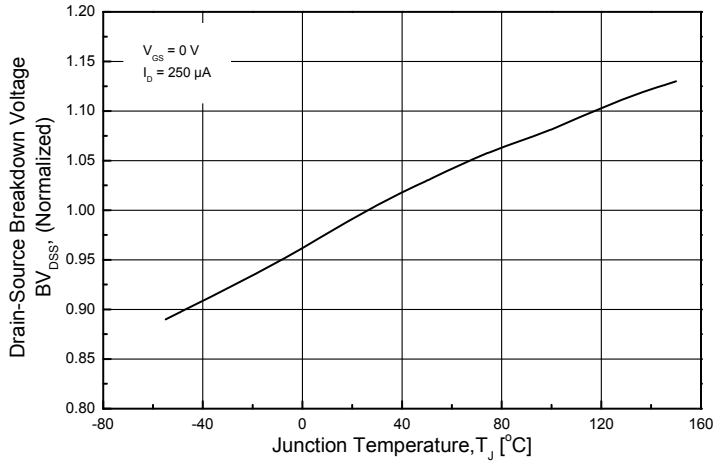
Electrical Characteristics : $T_C=25^\circ\text{C}$, unless otherwise noted

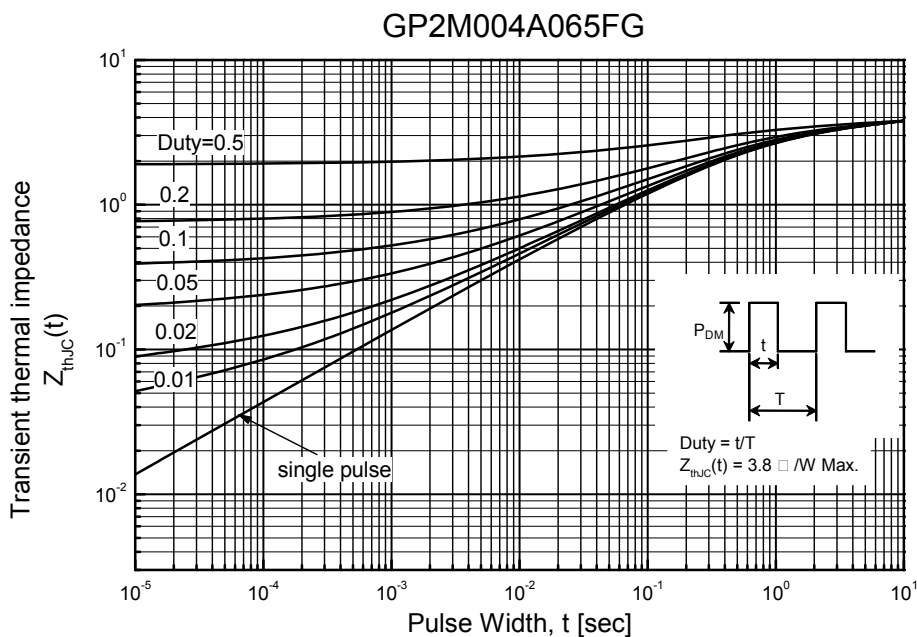
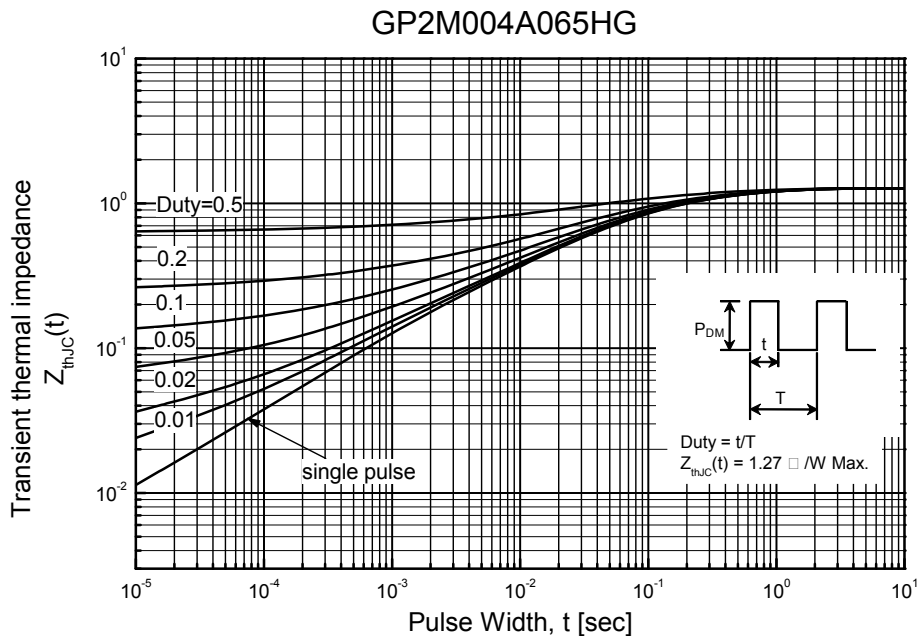
Parameter	Symbol	Test condition	Min	Typ	Max	Units
OFF						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS} = 0\text{ V}, I_D = 250\ \mu\text{A}$	650	--	--	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 650\text{ V}, V_{GS} = 0\text{ V}$	--	--	1	μA
		$V_{DS} = 520\text{ V}, T_C = 125^\circ\text{C}$	--	--	10	μA
Forward Gate-Source Leakage Current	I_{GSSF}	$V_{GS} = 30\text{ V}, V_{DS} = 0\text{ V}$	--	--	100	μA
Reverse Gate-Source Leakage Current	I_{GSSR}	$V_{GS} = -30\text{ V}, V_{DS} = 0\text{ V}$	--	--	-100	μA
ON						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\ \mu\text{A}$	3	--	5	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS} = 10\text{ V}, I_D = 2.0\text{ A}$	--	2.0	2.4	Ω
Forward Transconductance ^(Note 4)	g_{FS}	$V_{DS} = 30\text{ V}, I_D = 2.0\text{ A}$	--	6.5	--	S
DYNAMIC						
Input Capacitance	C_{iss}	$V_{DS} = 25\text{ V}, V_{GS} = 0\text{ V},$ $f = 1.0\text{ MHz}$	--	642	--	pF
Output Capacitance	C_{oss}		--	67	--	pF
Reverse Transfer Capacitance	C_{rss}		--	9.6	--	pF
SWITCHING						
Turn-On Delay Time ^(Note 4,5)	$t_{d(on)}$	$V_{DD} = 325\text{ V}, I_D = 4.0\text{ A},$ $R_G = 25\ \Omega$	--	19	--	ns
Turn-On Rise Time ^(Note 4,5)	t_r		--	22	--	ns
Turn-Off Delay Time ^(Note 4,5)	$t_{d(off)}$		--	50	--	ns
Turn-Off Fall Time ^(Note 4,5)	t_f		--	18	--	ns
Total Gate Charge ^(Note 4,5)	Q_g	$V_{DS} = 520\text{ V}, I_D = 4.0\text{ A},$ $V_{GS} = 10\text{ V}$	--	15	--	nC
Gate-Source Charge ^(Note 4,5)	Q_{gs}		--	3	--	nC
Gate-Drain Charge ^(Note 4,5)	Q_{gd}		--	7	--	nC
SOURCE DRAIN DIODE						
Maximum Continuous Drain-Source Diode Forward Current	I_S	----	--	--	4	A
Maximum Pulsed Drain-Source Diode Forward Current	I_{SM}	----	--	--	16	A
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS} = 0\text{ V}, I_S = 4.0\text{ A}$	--	--	1.5	V
Reverse Recovery Time ^(Note 4)	t_{rr}	$V_{GS} = 0\text{ V}, I_S = 4.0\text{ A}$ $di_F / dt = 100\text{ A}/\mu\text{s}$	--	328	--	ns
Reverse Recovery Charge ^(Note 4)	Q_{rr}		--	1.7	--	μC

Note :

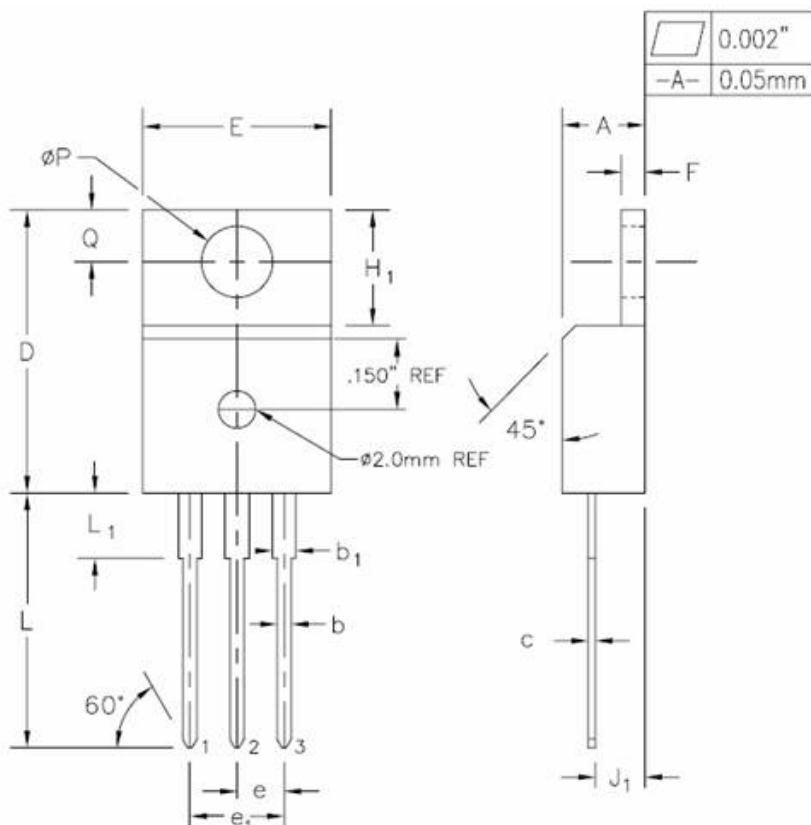
1. Repeated rating : Pulse width limited by safe operating area
2. $L=23.8\text{mH}, I_{AS} = 4.0\text{A}, V_{DD} = 50\text{V}, R_G = 25\Omega,$ Starting $T_J = 25^\circ\text{C}$
3. $I_{SD} \leq 4.0\text{A}, di/dt \leq 200\text{A}/\mu\text{s}, V_{DD} \leq BV_{DS},$ Starting $T_J = 25^\circ\text{C}$
4. Pulse Test : Pulse width $\leq 300\mu\text{s},$ Duty Cycle $\leq 2\%$
5. Essentially Independent of Operating Temperature Typical Characteristics





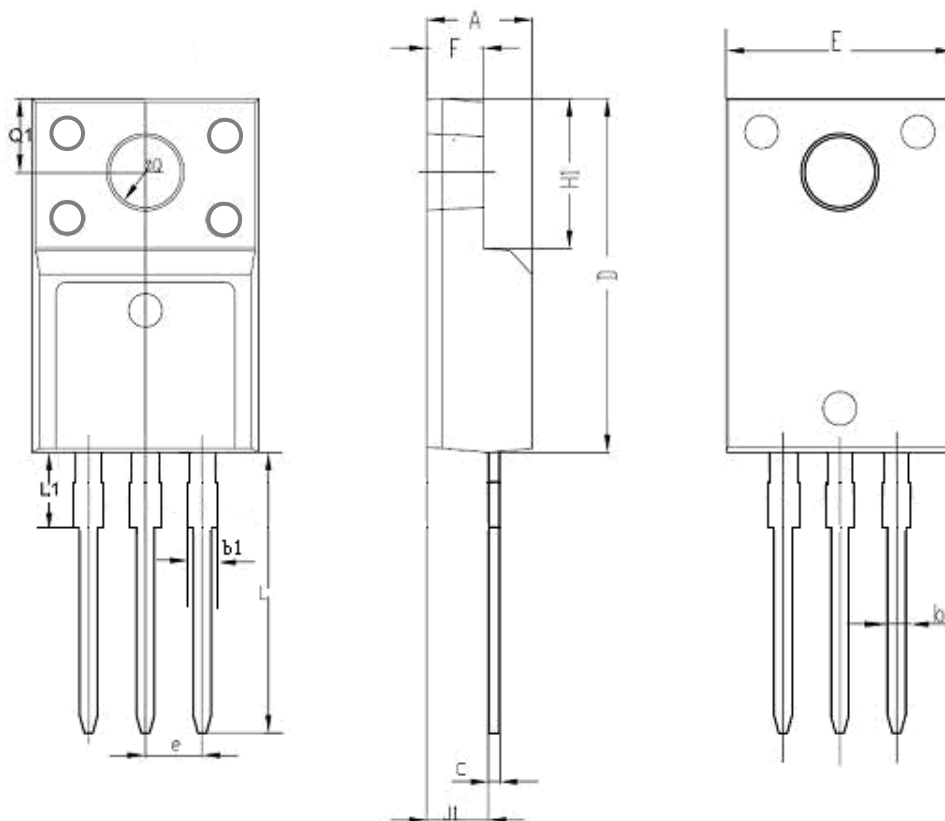


TO-220AB-3L MECHANICAL DATA



SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	0.170	0.180	4.32	4.57	
b	0.028	0.036	0.71	0.91	
b ₁	0.045	0.055	1.15	1.39	
c	0.014	0.021	0.36	0.53	
D	0.590	0.610	14.99	15.49	
E	0.395	0.410	10.04	10.41	
e	0.100 TYP.		2.54 TYP.		
e ₁	0.200 BSC		5.08 BSC		
F	0.048	0.054	1.22	1.37	
H ₁	0.235	0.255	5.97	6.47	
J ₁	0.100	0.110	2.54	2.79	
L	0.530	0.550	13.47	13.97	
L ₁	0.130	0.150	3.31	3.81	2
øP	0.149	0.153	3.79	3.88	
Q	0.102	0.112	2.60	2.84	

TO-220F-3L MECHANICAL DATA



SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	0.178	0.194	4.53	4.93	
b	0.028	0.036	0.71	0.91	
C	0.018	0.024	0.45	0.60	
D	0.617	0.633	15.67	16.07	
E	0.392	0.408	9.96	10.36	
e	0.100 TYP.		2.54TYP.		
H1	0.256	0.272	6.50	6.90	
J1	0.101	0.117	2.56	2.96	
L	0.503	0.519	12.78	13.18	
ϕQ	0.117	0.133	2.98	3.38	
b_1	0.045	0.055	1.15	1.39	
L_1	0.114	0.130	2.9	3.3	
Q_1	0.122	0.138	3.10	3.50	
F	0.092	0.108	2.34	2.74	